MOSFET – P-Channel, TSOP-6

-3.5 A, -30 V

Features

- Ultra Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- Miniature TSOP-6 Surface Mount Package
- Pb-Free Package is Available

Applications

• Power Management in Portable and Battery–Powered Products, i.e.: Cellular and Cordless Telephones, and PCMCIA Cards

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted.)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	-30	Volts
Gate-to-Source Voltage - Continuous	V _{GS}	±20.0	Volts
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$ Drain Current - Continuous @ $T_A = 25^{\circ}C$ - Pulsed Drain Current ($T_p < 10 \mu$ S) Maximum Operating Power Dissipation Maximum Operating Drain Current	R _{eJA} Pd I _D Pd I _{DM} I _D	62.5 2.0 -3.5 -20 1.0 -2.5	°C/W Watts Amps Amps Watts Amps
Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ $T_A = 25^{\circ}C$ Drain Current - Continuous @ $T_A = 25^{\circ}C$ - Pulsed Drain Current ($T_p < 10 \mu$ S) Maximum Operating Power Dissipation Maximum Operating Drain Current	R _{eJA} Pd I _D I _{DM} Pd I _D	128 1.0 -2.5 -14 0.5 -1.75	°C/W Watts Amps Amps Watts Amps
Operating and Storage Temperature Range	T _J , T _{stg}	–55 to 150	°C
Maximum Lead Temperature for Soldering Purposes for 10 Seconds	ΤL	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

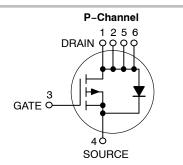
- Mounted onto a 2" square FR-4 board (1 in sq, 2 oz. Cu. 0.06" thick single sided), t < 5.0 seconds.
- Mounted onto a 2" square FR-4 board (1 in sq, 2 oz. Cu. 0.06" thick single sided), operating to steady state.

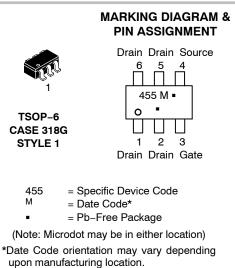


ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} TYP	I _D Max
–30 V	100 mΩ @ –10 V	-3.5 A





ORDERING INFORMATION

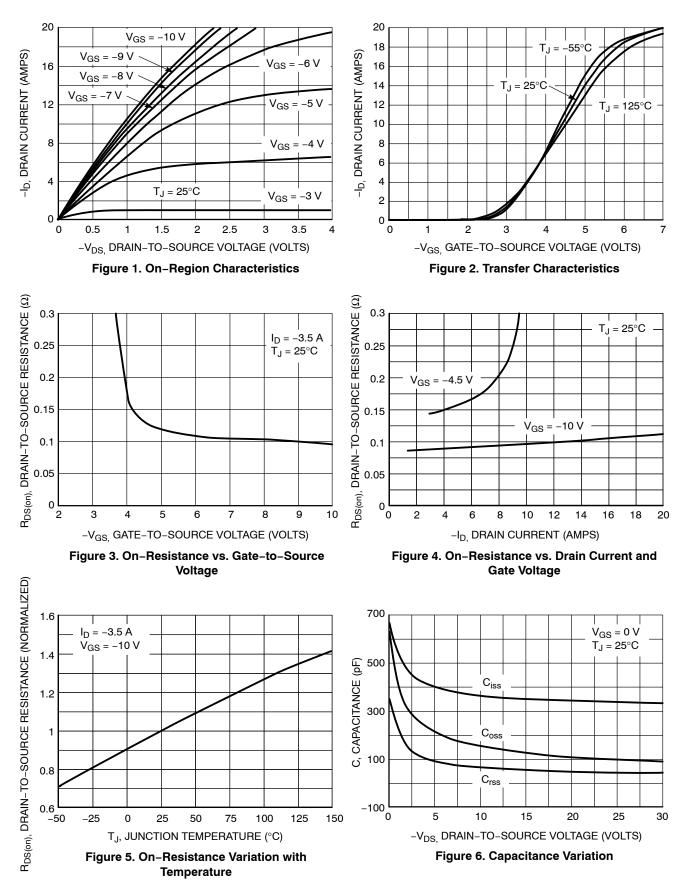
Device	Package	Shipping [†]
NTGS3455T1	TSOP-6	3000 Tape & Reel
NTGS3455T1G	TSOP-6 (Pb-Free)	3000 Tape & Reel

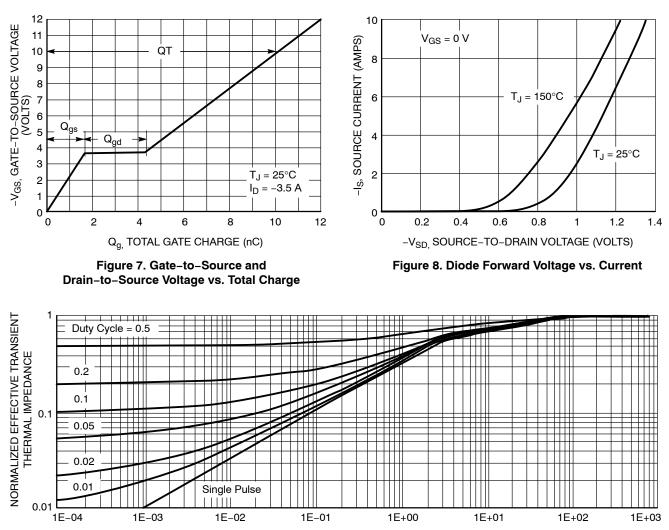
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted) (Notes 3 & 4)

Cha	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						•
Drain–Source Breakdown Voltage (V_{GS} = 0 Vdc, I_D = –10 μ A)			-30	_	_	Vdc
Zero Gate Voltage Drain Current ($V_{GS} = 0 Vdc, V_{DS} = -30 Vdc, T_J = 25^{\circ}C$) ($V_{GS} = 0 Vdc, V_{DS} = -30 Vdc, T_J = 70^{\circ}C$)		I _{DSS}			-1.0 -5.0	μAdc
Gate-Body Leakage Current (V _{GS} = -20.0 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	_	_	-100	nAdc
Gate-Body Leakage Current (V _{GS} = +20.0 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	_	100	nAdc
ON CHARACTERISTICS					•	•
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = -250 \ \mu Adc$)		V _{GS(th)}	-1.0	-1.87	-3.0	Vdc
Static Drain–Source On–State Resistance ($V_{GS} = -10$ Vdc, $I_D = -3.5$ Adc) ($V_{GS} = -4.5$ Vdc, $I_D = -2.7$ Adc)		R _{DS(on)}		0.094 0.144	0.100 0.170	Ω
Forward Transconductance $(V_{DS} = -15 \text{ Vdc}, I_D = -3.5 \text{ Adc})$		9FS	-	6.0	_	mhos
DYNAMIC CHARACTERISTICS						•
Total Gate Charge		Q _{tot}	-	9.0	13	nC
Gate-Source Charge	(V _{DS} = -15 Vdc, V _{GS} = -10 Vdc, I _D = -3.5 Adc)	Q _{gs}	-	2.5	-	
Gate-Drain Charge		Q _{gd}	-	2.0	-	
Input Capacitance		C _{iss}	-	480	-	pF
Output Capacitance	(V _{DS} = -5.0 Vdc, V _{GS} = 0 Vdc, f = 1.0 MHz)	C _{oss}	-	220	-	
Reverse Transfer Capacitance	,	C _{rss}	-	60	-	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time		t _{d(on)}	-	10	20	ns
Rise Time	(V _{DD} = −20 Vdc, I _D = −1.0 Adc,	t _r	-	15	30	
Turn-Off Delay Time	$V_{GS} = -10$ Vdc, $R_g = 6.0 \Omega$)	t _{d(off)}	-	20	35	
Fall Time		t _f	-	10	20	1
Reverse Recovery Time	(I _S = -1.7 Adc, dI _S /dt = 100 A/µs)	t _{rr}	-	30	-	ns
BODY-DRAIN DIODE RATINGS						
Diode Forward On-Voltage	$(I_{S} = -1.7 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$	V _{SD}	-	-0.90	-1.2	Vdc
Diode Forward On-Voltage	(I _S = -3.5 Adc, V _{GS} = 0 Vdc)	V _{SD}	-	-1.0	-	Vdc

Indicates Pulse Test: P.W. = 300 μsec max, Duty Cycle = 2%.
Class 1 ESD rated – Handling precautions to protect against electrostatic discharge are mandatory.





SQUARE WAVE PULSE DURATION (sec)

Figure 9. Normalized Thermal Transient Impedance, Junction-to-Ambient

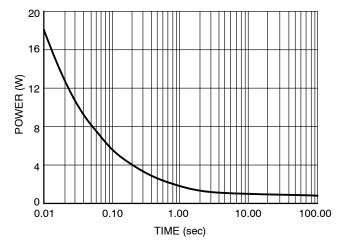


Figure 10. Single Pulse Power





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